Zener Diodes Panasonic

# MALD068XG

## Silicon planar type

#### For ESD protection

#### Overview

MALD068XG is optimal for cell phones and AV application, all types of  $\ensuremath{\mathrm{I/O}}$  circuits.

It is possible to protect against forward and reverse surges.

#### Features

- High resistance to surge voltages: 20 kV guaranteed
- Low terminal capacitance C<sub>t</sub> for low loss, low distortion, and good retention of signal waveforms.

### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                  | Symbol          | Rating      | Unit |  |
|----------------------------|-----------------|-------------|------|--|
| Peak pulse current *1      | $I_{PP}$        | 3           | A    |  |
| Peak pulse power *1        | P <sub>PP</sub> | 33          | W    |  |
| Total power dissipation *2 | $P_{T}$         | 150         | mW   |  |
| Junction temperature *3    | $T_j$           | 150         | °C   |  |
| Storage temperature        | $T_{stg}$       | -55 to +150 | °C   |  |
| Electrostatic discharge    | ESD             | ±20         | kV   |  |

- Note) \*1: Test method: IEC61000-4-5 (tp =  $8/20 \mu s$ , Unrepeated)
  - \*2: Test method: IEC61000-4-2 (C = 150 pF, R = 330  $\Omega$ , Contact discharge: 10 times)
  - \*3: P<sub>T</sub> = 150 mW achieved with a printed circuit board.

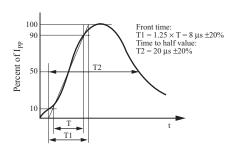
## ■ Package

- Code
  - SSSMini2-F3
- Pin Name
  - 1: Cathode
  - 2: Cathode
- Marking Symbol: A

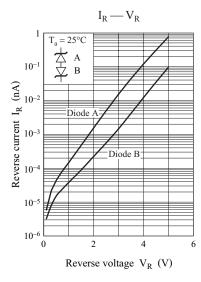
### ■ Electrical Characteristics $T_a = 25$ °C±3°C

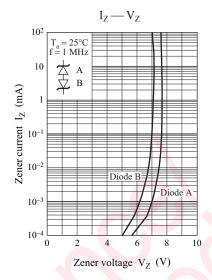
| Parameter            | Symbol         | Conditions                                       | Min | Тур | Max  | Unit |
|----------------------|----------------|--|-----|-----|------|------|
| Breakdown voltage *1 | $V_{BR}$       | $I_Z = 5 \text{ mA}$                             | 5.8 | 7.2 | 8.8  | V    |
| Clamping voltage *2  | $V_{\rm C}$    | $I_{PP} = 3.0 \text{ A, tp} = 8/20  \mu\text{s}$ |     |     | 11.0 | Ω    |
| Reverse current      | $I_R$          | $V_R = 3.5 \text{ V}$                            |     |     | 500  | nA   |
| Terminal capacitance | C <sub>t</sub> | $V_R = 0 V$ , $f = 1 MHz$                        |     | 25  |      | pF   |

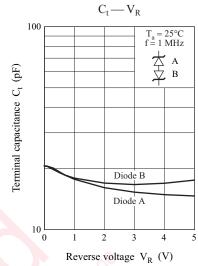
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2.  $*1:V_{BR}$  guaranted 20 ms after current flow.
    - \*2:Pulse Waveform
  - 3. Absolute frequency of input and output is 5 MHz



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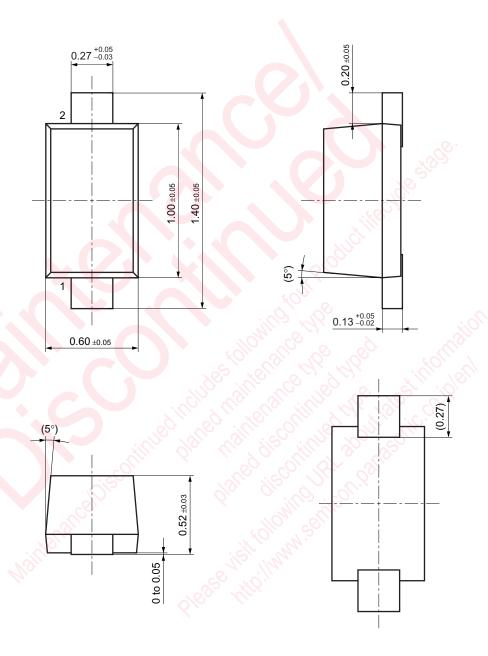






SSSMini2-F3

Unit: mm



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